NSN 5961-01-501-9157

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-501-9157 **Inclosure Material:** Metal **Overall Length:** Between 0.130 inches and 0.146 inches **Overall Diameter:** Between 0.063 inches and 0.067 inches **End Application:** Nuclear power plants **Mounting Facility Quantity: Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.00 regulator voltage, dc and 11.40 reverse voltage, instantaneous **Current Rating Per Characteristic:** 0.50 microamperes collector current, dc peak **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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